

Chapter 1

NV-NV CR under transverse or low fields: application to magnetometry

(mentionner l'article ici !)... The main motivation for this study was the potential to use NV-NV CR as a low field magnetometry protocol. Indeed, while NV-NV CR lines can be used to perform magnetometry with non zero fields [les russes], there are several advantages to use NV-NV CR as close to the zero magnetic field region, in particular the non dependence of the magnetic field orientation with respect to the crystal lattice. The behavior of

1.1 NV spin Hamiltonian under low and transverse fields

Before looking at the NV-NV CR in the low or transverse field regime, we first need to consider how the general NV physics is modified under those regimes, and in particular we need to look at the modifications of the spin Hamiltonian and the change in the eigenstates.

1.1.1 NV spin Hamiltonian in zero external magnetic field

In the absence of external magnetic field, we have to take into account other elements which would otherwise be of second order in the spin Hamiltonian. These elements are: the random local magnetic fields caused by paramagnetic impurities, the local electric field caused by charged impurities, and the crystal strain [1, 2, 3]. The hyperfine splitting due to nearby nuclei will be considered separately, although to a large extent it behaves like a local magnetic field.

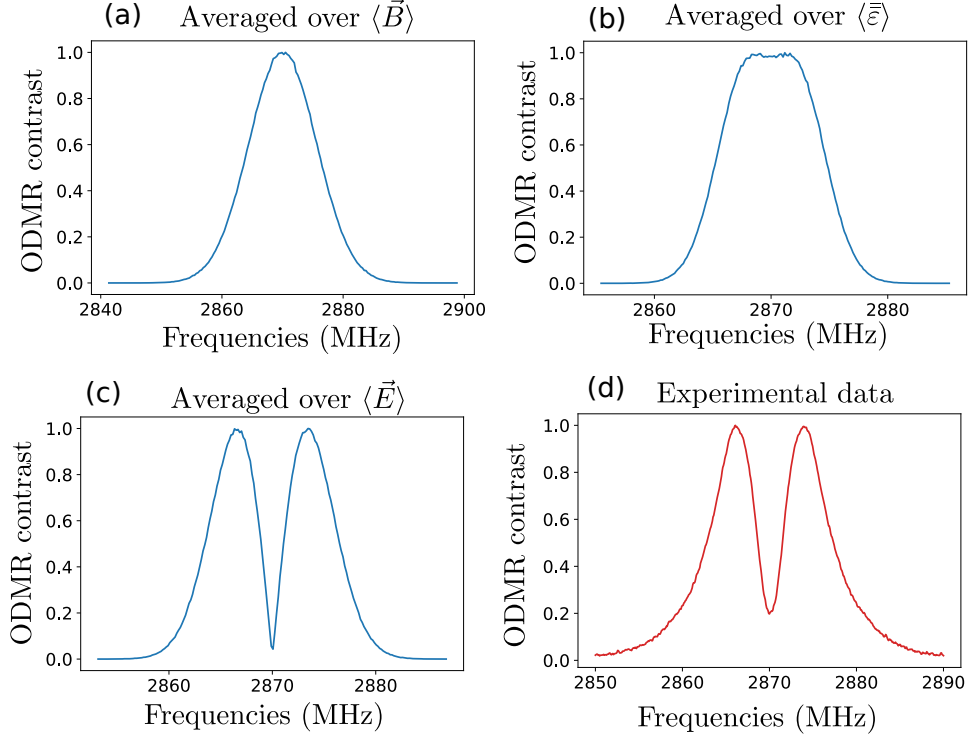


Figure 1.1: Simulations of inhomogeneous zero field ODMR when sampling various parameters. a) Simulation when sampling each components of the magnetic field over a Gaussian of deviation $\sigma = 2$ G. b) Simulation when sampling each components of the strain tensor $\vec{\varepsilon}$ over a Gaussian of deviation $\sigma = 2 \cdot 10^{-4}$. c) Simulation when sampling each components of the electric field over a Gaussian of deviation $\sigma = 2 \cdot 10^5$ V/cm. d) Experimental ODMR spectrum in zero external field taken on sample ADM-150-2

Due to the large zero field splitting $D = 2870 \text{ MHz}$ between the $|0\rangle$ and $|\pm 1\rangle$ states, we will consider the $|0\rangle$ to always be an eigenstate of the spin Hamiltonian under zero external field (which is equivalent to say that we neglect the terms in $|0\rangle \langle \pm 1|$ in the spin Hamiltonian). The problem is then reduced to the $\{|-1\rangle, |+1\rangle\}$ subsystem.

The NV⁻ spin Hamiltonian in the $\{|-1\rangle, |+1\rangle\}$ basis can be written as [2]:

$$\mathcal{H} = \begin{pmatrix} D - \gamma_e B_{\parallel} + f_{\parallel}(\mathbf{E}) + g_{\parallel}(\vec{\varepsilon}) & f_{\perp}(\mathbf{E}) + g_{\perp}(\vec{\varepsilon}) \\ f_{\perp}^*(\mathbf{E}) + g_{\perp}^*(\vec{\varepsilon}) & D + \gamma_e B_{\parallel} + f_{\parallel}(\mathbf{E}) + g_{\parallel}(\vec{\varepsilon}) \end{pmatrix}, \quad (1.1)$$

where B_{\parallel} is the component of the magnetic field along the NV axis, and $f_{\parallel}, f_{\perp}, g_{\perp}$, and g_{\parallel} are functions of the electric field \mathbf{E} and the strain tensor $\vec{\varepsilon}$, whose expressions are:

$$f_{\parallel}(\mathbf{E}) = d_{\parallel} E_z, \quad (1.2)$$

$$f_{\perp}(\mathbf{E}) = d_{\perp} (E_x + iE_y), \quad (1.3)$$

$$g_{\parallel}(\bar{\epsilon}) = h_{41}(\epsilon_{xx} + \epsilon_{yy}) + h_{43}\epsilon_{zz}, \quad (1.4)$$

$$g_{\perp}(\bar{\epsilon}) = \frac{1}{2} \left[h_{16}(\epsilon_{zx} + i\epsilon_{zy}) + h_{15} \left(\frac{\epsilon_{yy} - \epsilon_{xx}}{2} + i\epsilon_{xy} \right) \right], \quad (1.5)$$

where $d_{\parallel} = 0.35$ Hz cm/V and $d_{\perp} = 17$ Hz cm/V have been measured experimentally [4], and $h_{43} = 2300$ MHz, $h_{41} = -6420$ MHz, $h_{15} = 5700$ MHz and $h_{16} = 19660$ MHz were computed through DFT [2] and show reasonable agreement with experiments [5].

Importantly, as pointed in [3] we notice that both the electric field and the strain have a *shifting* component (f_{\parallel} and g_{\parallel}) which shifts equally both eigenstates of the Hamiltonian, and a *splitting* component (f_{\perp} and g_{\perp}) which splits in energy the two eigenstates.

The main difference between the electric field and the strain is in the numerical prefactors of these components: for the electric field, the splitting parameter d_{\perp} is ~ 50 times higher than the shifting parameter d_{\parallel} , which will result on average to a strong energy split without much shifting. For the strain however, the splitting parameters h_{15} and h_{16} are only ~ 3 times higher than the shifting parameters h_{43} and h_{41} . The shift in energy will therefore tend to blur the energy split when averaging over a large number of spins.

Fig. 1.1 shows a simulation of how each parameters of the spin Hamiltonian - local magnetic field, local electric field and strain - affects the zero external field ODMR profile. To do these simulations, I sampled each parameters separately 10^6 times and plotted the histogram of the two eigenvalues of the Hamiltonian written in eq. 1.1. Fig. 1.1-d) shows an experimental zero field ODMR spectrum, typical of what we observe with dense NV ensembles.

Experimentally, almost all our samples show the characteristic two bumps in zero external field ODMR. Given the simulation results, the only parameter that can give rise to this shape is the electric field. We will therefore consider that the NV Hamiltonian of our samples is dominated by the local electric field, and more specifically by the transverse electric field $E_{\perp} \equiv E_x + iE_y$ given the ratio between d_{\perp} and d_{\parallel} .

We will then adopt the following simplified Hamiltonian for the zero external field regime:

$$\mathcal{H} = \begin{pmatrix} D & 0 & d_{\perp} E_{\perp}^* \\ 0 & 0 & 0 \\ d_{\perp} E_{\perp} & 0 & D \end{pmatrix}, \quad (1.6)$$

whose eigenvectors are $|0\rangle$ and $|\pm\rangle$ of eigenvalues 0 and $D \pm d_{\perp}|E_{\perp}|$, where $|\pm\rangle$ are defined as:

$$|\pm\rangle = \frac{|+1\rangle \pm e^{-i\phi_E} |-1\rangle}{\sqrt{2}}, \quad (1.7)$$

where $\tan(\phi_E) = E_y/E_x$.

1.1.2 NV spin Hamiltonian under purely transverse magnetic field

We will consider here the case of purely transverse magnetic field with respect to the NV axis, i.e. $\mathbf{B} = B_x \hat{e}_x + B_y \hat{e}_y$, and more specifically the regime where $d_{\perp} E_{\perp} < \frac{(\gamma_e B_{\perp})^2}{D} \ll D$. In practice, this generally means $20 \text{ G} \lesssim B_{\perp} \lesssim 200 \text{ G}$.

In this regime, the NV Hamiltonian eigenstates are similar to the case dominated by the transverse electric field and can be written $\approx |0\rangle, |\pm\rangle$ [6, 7], of eigenvalues $\approx -\frac{(\gamma_e B_{\perp})^2}{D}, D$ and $D + \frac{(\gamma_e B_{\perp})^2}{D}$, where:

$$|\pm\rangle = \frac{|+1\rangle \pm e^{-2i\phi_B} |-1\rangle}{\sqrt{2}}, \quad (1.8)$$

and $\tan(\phi_B) = B_y/B_x$.

For the case where $d_{\perp} E_{\perp} \sim \frac{(\gamma_e B_{\perp})^2}{D}$ and $\phi_E \neq 2\phi_B$, the eigenstates of the Hamiltonian are still $|0\rangle, |\pm\rangle$ with a relative angle ϕ in between ϕ_E and $2\phi_B$.

In conclusion, whenever the spin Hamiltonian is dominated by a transverse field, either electric or magnetic, we can consider that the eigenstates of the spin Hamiltonian are $|0\rangle, |-1\rangle$ and $|+1\rangle$, whereas when the spin Hamiltonian is dominated by the longitudinal magnetic field, the spin eigenstates are $|0\rangle, |-1\rangle$ and $|+1\rangle$.

1.1.3 Hyperfine coupling and inhomogeneous broadening

Jambonneau mais pas que. Foutre des ESR si possible. Je vais en chier en vrai.

1.2 Modification of NV-NV CR in the transverse field dominated regime

In this part, we will study the cross-relaxation between NV centers whose spin Hamiltonian is dominated by a transverse field, either magnetic or electric. This is an important regime because it corresponds to the low magnetic field region where the electric field dominates, which is the region for which we want to implement our magnetometry protocol. We will also

study here the double flip CR processes which we had neglected in the last chapter.

1.2.1 NV-NV CR under low magnetic field

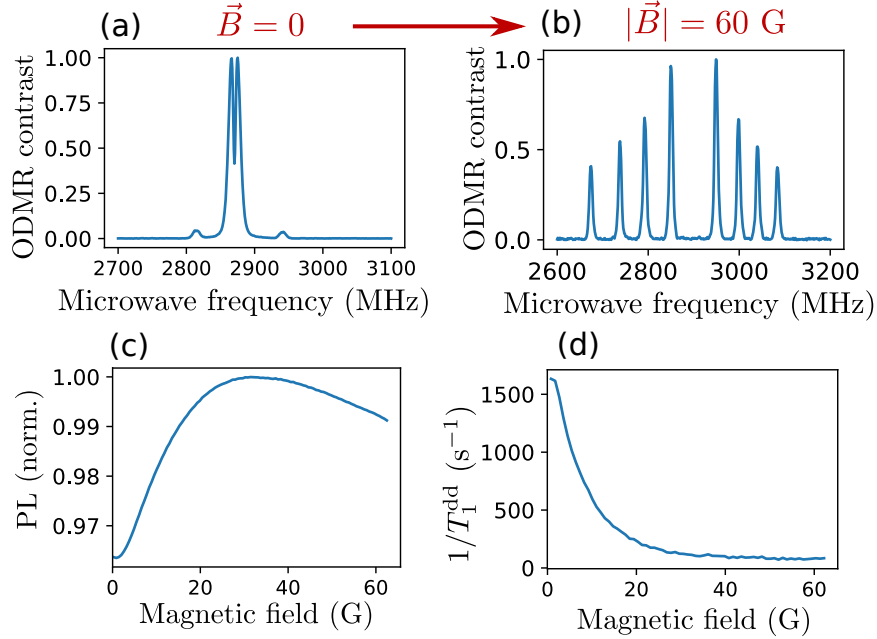


Figure 1.2: tata. Changer les T1 avec T1ph=5ms

We will start by showing that NV-NV CR behaves differently in the low magnetic field regime compared to the longitudinal field dominated regime which we studied in the last chapter.

The main issue with studying NV-NV CR in low to zero magnetic field is that there are many competing effects happening simultaneously, with few buttons to adjust to isolate each effects.

Fig. 1.2-c) and d) for example shows the evolution of the NV PL and stretched lifetime T_1^{dd} , defined in the last chapter [REF], as the magnetic field is scanned from 0 to 60 G. The ODMR at the initial and final magnetic fields are shown in Fig. 1.2-a) and b).

While it is clear that the spin lifetime, as well as the PL, increases when the magnetic field, there is no clear indication that this is because of the specificity of the low field region. Indeed, the most likely explanation in this case is that the four classes of NV centers get split apart as the magnetic field increases, which reduces the density of resonant fluctuators for each NV centers.

Fig. 1.3 presents a way to circumvent this issue: by applying the magnetic field along the [100] crystalline axis, we can make sure that the four

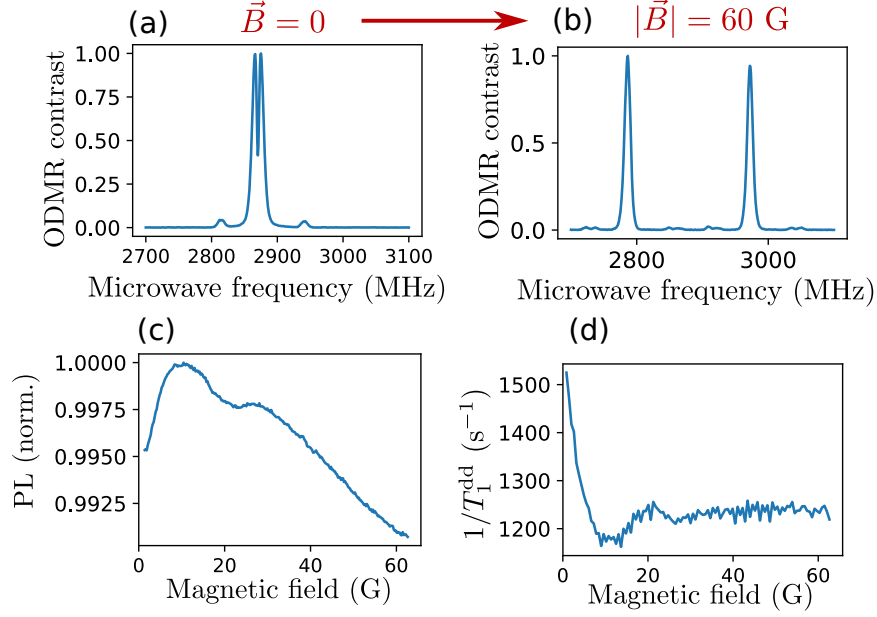


Figure 1.3: Same measurements as Fig. 1.2, still on sample ADM-150-1, but with \mathbf{B} along the $[100]$ axis. Changer les T1 avec T1ph=5ms

classes of NV centers always stay resonant regardless of the magnetic field amplitude.

We can notice that there still is a decrease of both the PL and T_1^{dd} in low field, although considerably smaller than the previous case: in Fig. 1.2, T_1^{dd} was reduced by a factor of [REF] in zero field, whereas in Fig. 1.3, it was only reduced by a factor of [REF]. The main reason for the PL and T_1 drop was indeed the co-resonance between the four classes.

Nevertheless, the fact that there is a drop in zero field when $\mathbf{B} \parallel [100]$ cannot be explained by using only the inter-class resonances. There are some additional depolarization mechanisms which are proper to the zero field region. We should also note that, while the zero-field PL contrast is bigger in Fig. 1.2-c) than in Fig. 1.3-c), the slope, which is the limiting factor for sensing ability, is actually very similar in both cases with a value $\sim [REF] \text{ G}^{-1}$.

1.2.2 Potential causes for low field depolarization

Tutut, tu fais le hyperfin avant de continuer.

Change in eigenstates

Double flips

Change in T_2^*

1.2.3 NV-NV CR under purely transverse magnetic field

Sa mère, faut que je replotte tous les T1 avec t1ph=5 ms.

1.2.4 Other potential causes

Alignment : 100 et perp (utiliser la carte) Pola laser

1.3 Low field magnetometry

Ne pas oublier (ou alors en perspective, c'est bien aussi) : les deux adamas du 20210927 avec le petit et le gros

1.4 Conclusion and perspectives

- Improvement to the sensitivity : Scale up, material optimization (15N !)
 - Understand the impact of the various factors on the flip-flop CR and DQ CR: T_2^* , strain, local electric noise ...
 - Application for uneven surfaces, polycrystalline heteroepithaxy, low/no microwave environment (diamond anvil cells, bio sensing)

Bibliography

- [1] MW Doherty et al. “Theory of the ground-state spin of the NV- center in diamond”. In: *Physical Review B* 85.20 (2012), p. 205203.
- [2] Péter Udvarhelyi et al. “Spin-strain interaction in nitrogen-vacancy centers in diamond”. In: *Physical Review B* 98.7 (2018), p. 075201.
- [3] Thomas Mittiga et al. “Imaging the local charge environment of nitrogen-vacancy centers in diamond”. In: *Physical review letters* 121.24 (2018), p. 246402.
- [4] Eric Van Oort and Max Glasbeek. “Electric-field-induced modulation of spin echoes of NV centers in diamond”. In: *Chemical Physics Letters* 168.6 (1990), pp. 529–532.
- [5] Michael SJ Barson et al. “Nanomechanical sensing using spins in diamond”. In: *Nano letters* 17.3 (2017), pp. 1496–1503.
- [6] Ziwei Qiu et al. “Nuclear spin assisted magnetic field angle sensing”. In: *npj Quantum Information* 7.1 (2021), pp. 1–7.
- [7] Ziwei Qiu et al. “Nanoscale Electric Field Imaging with an Ambient Scanning Quantum Sensor Microscope”. In: *arXiv preprint arXiv:2205.03952* (2022).